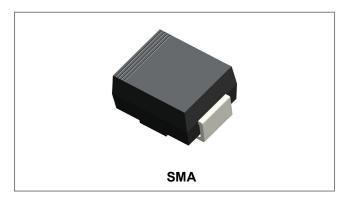






### SK23A SCHOTTKY RECTIFIER



#### **Features**

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term
- reliability
- Green products in compliance the ROHS directive
- Terminals finish: Tin Lead-free plated
- This is a Pb Free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### Maximum Ratings(limiting values, T<sub>C</sub> =25°C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	30	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>L</sub> =105°C, rectangular wave form	2	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	50	Α

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 2A, Pulse, T <sub>J</sub> = 25 °C	0.50	0.55	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	0.02	0.5	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 100 °C	0.5	20	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25  ^{\circ}C, f_{SIG} = 1MHz$	131	250	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nΗ
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%







## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +125	°C
Storage Temperature	$T_{stg}$	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ heta Jc}$	DC operation	8	°C/W
Approximate Weight	wt	-	0.06	g

### **Ratings and Characteristics Curves**

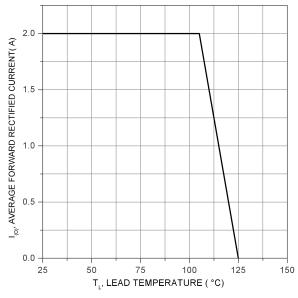


Fig.1 Forward Current Derating Curve

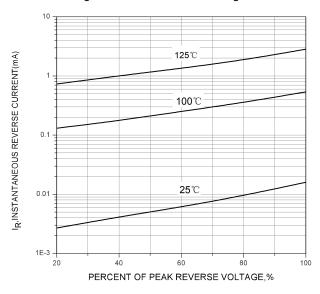


Fig.3 Typical Reverse Characteristics

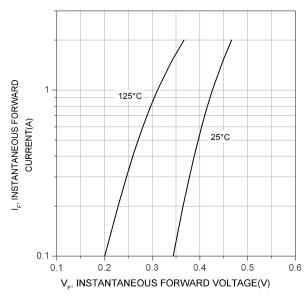


Fig.2 Typical Forward Characteristics

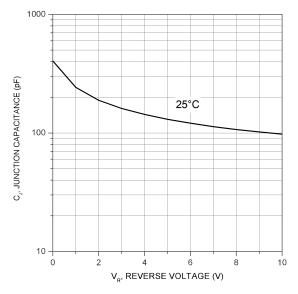


Fig.4 Typical Junction Capacitance

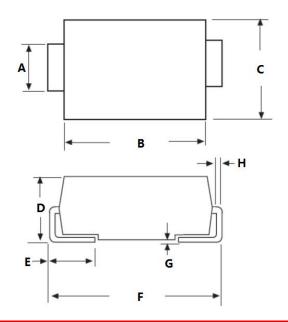
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### **Mechanical Dimensions SMA**



SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
А	1.25	1.65	0.049	0.065
В	3.95	4.6	0.156	0.181
С	2.25	2.95	0.089	0.116
D	1.95	2.9	0.077	0.114
E	0.75	1.6	0.03	0.063
F	4.8	5.6	0.189	0.22
G	0.05	0.2	0.002	0.008
Н	0.15	0.41	0.006	0.016

### **Ordering Information**

Device	Package	Shipping
SK23A	SMA	5000pcs / reel
SK23ATR	SMA	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**

SK23A

XXXXX

SK 2 3 A

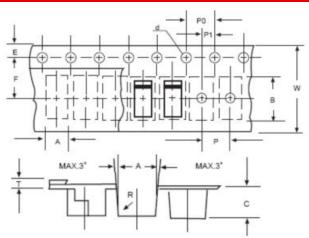
Where XXXXX is YYWWL

SK = Device Type 2 = Forward Current (2A) 3 = Reverse Voltage (30V) A = Package type

YY = Year WW = Week L = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

# **Carrier Tape Specification SMA**



SYMBOL	Millimeters		
STIVIBUL	Min.	Max.	
Α	2.97	3.17	
В	5.70	5.90	
C	2.32	2.52	
d	1.40	1.60	
Е	1.40	1.60	
F	5.60	5.70	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
Т	0.25	0.35	
W	11.80	12.20	

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